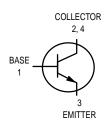
# NPN Silicon Planar Epitaxial Transistor

This NPN Silicon Epitaxial transistor is designed for use in linear and switching applications. The device is housed in the SOT-223 package which is designed for medium power surface mount applications.

- PNP Complement is PZT2907AT1
- The SOT-223 package can be soldered using wave or reflow.
- SOT-223 package ensures level mounting, resulting in improved thermal conduction, and allows visual inspection of soldered joints. The formed leads absorb thermal stress during soldering, eliminating the possibility of damage to the die.
- Available in 12 mm tape and reel
   Use PZT2222AT1 to order the 7 inch/1000 unit reel.
   Use PZT2222AT3 to order the 13 inch/4000 unit reel.



## **PZT2222AT1**

Motorola Preferred Device

SOT-223 PACKAGE NPN SILICON TRANSISTOR SURFACE MOUNT



#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	VCEO	40	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	75	Vdc
Emitter-Base Voltage (Open Collector)	V <sub>EBO</sub>	6.0	Vdc
Collector Current	IC	600	mAdc
Total Power Dissipation up to $T_A = 25^{\circ}C^{(1)}$	PD	1.5	Watts
Storage Temperature Range	T <sub>stg</sub>	- 65 to +150	°C
Junction Temperature	TJ	150	°C

#### THERMAL CHARACTERISTICS

Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	83.3	°C/W
Lead Temperature for Soldering, 0.0625" from case Time in Solder Bath	TL	260 10	°C Sec

#### **DEVICE MARKING**

P1F

### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic		Min	Max	Unit	
OFF CHARACTERISTICS					
Collector-Emitter Breakdown Voltage (I <sub>C</sub> = 10 mAdc, I <sub>B</sub> = 0)	V(BR)CEO	40	_	Vdc	
Collector-Base Breakdown Voltage (I <sub>C</sub> = 10 μAdc, I <sub>E</sub> = 0)	V(BR)CBO	75	_	Vdc	
Emitter-Base Breakdown Voltage (I <sub>E</sub> = 10 μAdc, I <sub>C</sub> = 0)	V(BR)EBO	6.0	_	Vdc	
Base-Emitter Cutoff Current (V <sub>CE</sub> = 60 Vdc, V <sub>BE</sub> = -3.0 Vdc)	I <sub>BEX</sub>	_	20	nAdc	
Collector-Emitter Cutoff Current (V <sub>CE</sub> = 60 Vdc, V <sub>BE</sub> = -3.0 Vdc)	ICEX	_	10	nAdc	
Emitter-Base Cutoff Current (V <sub>EB</sub> = 3.0 Vdc, I <sub>C</sub> = 0)	IEBO	_	100	nAdc	

<sup>1.</sup> Device mounted on an epoxy printed circuit board 1.575 inches x 1.575 inches x 0.059 inches; mounting pad for the collector lead min. 0.93 inches<sup>2</sup>. Thermal Clad is a trademark of the Bergquist Company

Preferred devices are Motorola recommended choices for future use and best overall value.

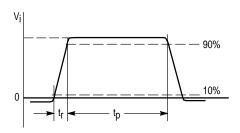
REV 2



### **PZT2222AT1**

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	Characteristic	Symbol	Min	Max	Unit
OFF CHARACT	ERISTICS (continued)				
Collector-Base C (V <sub>CB</sub> = 60 Vdc (V <sub>CB</sub> = 60 Vdc		I <sub>CBO</sub>	_ _	10 10	nAdc μAdc
ON CHARACTE	RISTICS				
(I <sub>C</sub> = 1.0 mAdc, (I <sub>C</sub> = 10 mAdc, (I <sub>C</sub> = 150 mAdc, (I <sub>C</sub> = 150 mAdc)	c, VCE = 10 Vdc) c, VCE = 10 Vdc) VCE = 10 Vdc, VCE = 10 Vdc, T <sub>A</sub> = -55°C) c, V <sub>C</sub> E = 10 Vdc) c, V <sub>C</sub> E = 1.0 Vdc) c, V <sub>C</sub> E = 1.0 Vdc) c, V <sub>C</sub> E = 1.0 Vdc)	hFE	35 50 70 35 100 50 40		_
$(I_C = 150 \text{ mAdd})$	Saturation Voltages c, I <sub>B</sub> = 15 mAdc) c, I <sub>B</sub> = 50 mAdc)	VCE(sat)	_ _	0.3 1.0	Vdc
	uration Voltages c, I <sub>B</sub> = 15 mAdc) c, I <sub>B</sub> = 50 mAdc)	VBE(sat)	0.6 —	1.2 2.0	Vdc
	, I <sub>C</sub> = 1.0 mAdc, f = 1.0 kHz) , I <sub>C</sub> = 10 mAdc, f = 1.0 kHz)	h <sub>ie</sub>	2.0 0.25	8.0 1.25	kΩ
	k Ratio , I <sub>C</sub> = 1.0 mAdc, f = 1.0 kHz) , I <sub>C</sub> = 10 mAdc, f = 1.0 kHz)	h <sub>re</sub>		8.0x10 <sup>-4</sup> 4.0x10 <sup>-4</sup>	_
	rent Gain c, I <sub>C</sub> = 1.0 mAdc, f = 1.0 kHz) c, I <sub>C</sub> = 10 mAdc, f = 1.0 kHz)	h <sub>fe</sub>	50 75	300 375	_
	te f, I <sub>C</sub> = 1.0 mAdc, f = 1.0 kHz) f, I <sub>C</sub> = 10 mAdc, f = 1.0 kHz)	h <sub>oe</sub>	5.0 25	35 200	μmhos
Noise Figure (VC	E = 10 Vdc, I <sub>C</sub> = 100 μAdc, f = 1.0 kHz)	F		4.0	dB
DYNAMIC CHA	RACTERISTICS				
	Bandwidth Product V <sub>CE</sub> = 20 Vdc, f = 100 MHz)	fT	300	_	MHz
Output Capacitar (V <sub>CB</sub> = 10 Vdc	nce , I <sub>E</sub> = 0, f = 1.0 MHz)	C <sub>c</sub>	_	8.0	pF
Input Capacitance (VEB = 0.5 Vdc	e c, I <sub>C</sub> = 0, f = 1.0 MHz)	C <sub>e</sub>	_	25	pF
SWITCHING TI	MES (T <sub>A</sub> = 25°C)			•	
Delay Time	(V <sub>CC</sub> = 30 Vdc, I <sub>C</sub> = 150 mAdc, I <sub>B(on)</sub> = 15 mAdc, V <sub>EB(off)</sub> = 0.5 Vdc)	<sup>t</sup> d	_	10	ns
Rise Time	Figure 1	t <sub>r</sub>	_	25	
Storage Time	$(V_{CC} = 30 \text{ Vdc}, I_{C} = 150 \text{ mAdc},$ $I_{B(on)} = I_{B(off)} = 15 \text{ mAdc})$	t <sub>S</sub>	_	225	ns
Fall Time	Figure 2	t <sub>f</sub>	_	60	



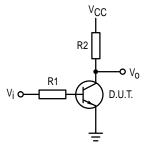
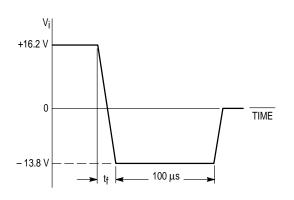


Figure 1. Input Waveform and Test Circuit for Determining Delay Time and Rise Time

 $\rm V_{i}$  = - 0.5 V to +9.9 V, V\_{CC} = +30 V, R1 = 619  $\Omega$ , R2 = 200  $\Omega$ .

PULSE GENERATOR:		
PULSE DURATION	t <sub>n</sub> ≤	200 ns
RISE TIME	t <sub>p</sub> ≤ t <sub>r</sub> ≤	2 ns
DUTY FACTOR	δ =	0.02



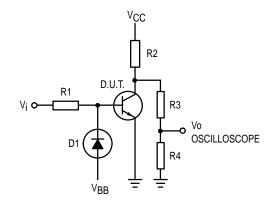
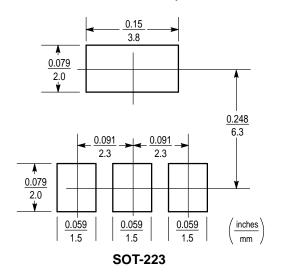


Figure 2. Input Waveform and Test Circuit for Determining Storage Time and Fall Time

#### INFORMATION FOR USING THE SOT-223 SURFACE MOUNT PACKAGE

#### MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to insure proper solder connection interface between the board and the package. With the correct pad geometry, the packages will self align when subjected to a solder reflow process.



**SOT-223 POWER DISSIPATION** 

The power dissipation of the SOT-223 is a function of the pad size. This can vary from the minimum pad size for soldering to a pad size given for maximum power dissipation. Power dissipation for a surface mount device is determined by  $\mathsf{TJ}_{(max)}$ , the maximum rated junction temperature of the die,  $\mathsf{R}_{\theta}\mathsf{JA}$ , the thermal resistance from the device junction to ambient, and the operating temperature,  $\mathsf{TA}$ . Using the values provided on the data sheet for the SOT-223 package,  $\mathsf{PD}$  can be calculated as follows:

$$P_D = \frac{T_{J(max)} - T_A}{R_{\theta,JA}}$$

The values for the equation are found in the maximum ratings table on the data sheet. Substituting these values into the equation for an ambient temperature  $T_A$  of 25°C, one can calculate the power dissipation of the device which in this case is 1.5 watts.

$$P_D = \frac{150^{\circ}C - 25^{\circ}C}{83.3^{\circ}C/W} = 1.5 \text{ watts}$$

The 83.3°C/W for the SOT-223 package assumes the use of the recommended footprint on a glass epoxy printed circuit board to achieve a power dissipation of 1.5 watts. There are other alternatives to achieving higher power dissipation from the SOT-223 package. One is to increase the area of the collector pad. By increasing the area of the collector pad, the power dissipation can be increased. Although the power

dissipation can almost be doubled with this method, area is taken up on the printed circuit board which can defeat the purpose of using surface mount technology. A graph of  $R_{\theta JA}$  versus collector pad area is shown in Figure 3.

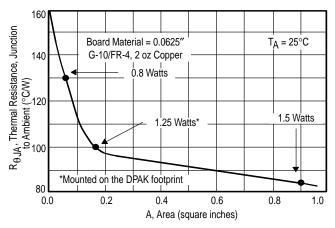


Figure 3. Thermal Resistance versus Collector Pad Area for the SOT-223 Package (Typical)

Another alternative would be to use a ceramic substrate or an aluminum core board such as Thermal Clad™. Using a board material such as Thermal Clad, an aluminum core board, the power dissipation can be doubled using the same footprint.

#### **SOLDER STENCIL GUIDELINES**

Prior to placing surface mount components onto a printed circuit board, solder paste must be applied to the pads. A solder stencil is required to screen the optimum amount of solder paste onto the footprint. The stencil is made of brass

or stainless steel with a typical thickness of 0.008 inches. The stencil opening size for the SOT-223 package should be the same as the pad size on the printed circuit board, i.e., a 1:1 registration.

#### **SOLDERING PRECAUTIONS**

The melting temperature of solder is higher than the rated temperature of the device. When the entire device is heated to a high temperature, failure to complete soldering within a short time could result in device failure. Therefore, the following items should always be observed in order to minimize the thermal stress to which the devices are subjected.

- Always preheat the device.
- The delta temperature between the preheat and soldering should be 100°C or less.\*
- When preheating and soldering, the temperature of the leads and the case must not exceed the maximum temperature ratings as shown on the data sheet. When using infrared heating with the reflow soldering method, the difference should be a maximum of 10°C.

- The soldering temperature and time should not exceed 260°C for more than 10 seconds.
- When shifting from preheating to soldering, the maximum temperature gradient should be 5°C or less.
- After soldering has been completed, the device should be allowed to cool naturally for at least three minutes.
   Gradual cooling should be used as the use of forced cooling will increase the temperature gradient and result in latent failure due to mechanical stress.
- Mechanical stress or shock should not be applied during cooling
- \* Soldering a device without preheating can cause excessive thermal shock and stress which can result in damage to the device.

#### TYPICAL SOLDER HEATING PROFILE

For any given circuit board, there will be a group of control settings that will give the desired heat pattern. The operator must set temperatures for several heating zones, and a figure for belt speed. Taken together, these control settings make up a heating "profile" for that particular circuit board. On machines controlled by a computer, the computer remembers these profiles from one operating session to the next. Figure 4 shows a typical heating profile for use when soldering a surface mount device to a printed circuit board. This profile will vary among soldering systems but it is a good starting point. Factors that can affect the profile include the type of soldering system in use, density and types of components on the board, type of solder used, and the type of board or substrate material being used. This profile shows temperature versus time. The line on the graph shows the

actual temperature that might be experienced on the surface of a test board at or near a central solder joint. The two profiles are based on a high density and a low density board. The Vitronics SMD310 convection/infrared reflow soldering system was used to generate this profile. The type of solder used was 62/36/2 Tin Lead Silver with a melting point between 177–189°C. When this type of furnace is used for solder reflow work, the circuit boards and solder joints tend to heat first. The components on the board are then heated by conduction. The circuit board, because it has a large surface area, absorbs the thermal energy more efficiently, then distributes this energy to the components. Because of this effect, the main body of a component may be up to 30 degrees cooler than the adjacent solder joints.

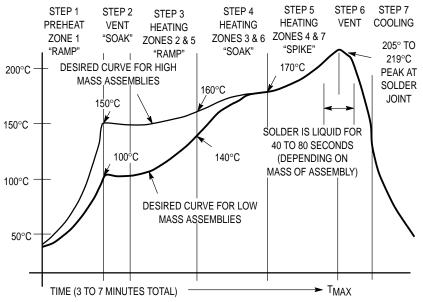
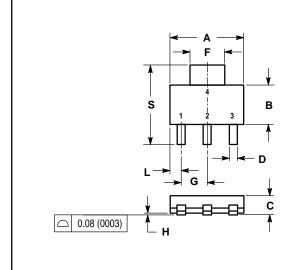


Figure 4. Typical Solder Heating Profile

#### PACKAGE DIMENSIONS





CASE 318E-04 ISSUE H TO-261AA

#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIM	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.249	0.263	6.30	6.70
В	0.130	0.145	3.30	3.70
С	0.060	0.068	1.50	1.75
D	0.024	0.035	0.60	0.89
F	0.115	0.126	2.90	3.20
G	0.087	0.094	2.20	2.40
Н	0.0008	0.0040	0.020	0.100
J	0.009	0.014	0.24	0.35
K	0.060	0.078	1.50	2.00
L	0.033	0.041	0.85	1.05
М	0 °	10 °	0 °	10 °
S	0.264	0.287	6.70	7.30

STYLE 1:

PIN 1. BASE

2. COLLECTOR

B. EMITTER

4. COLLECTOR

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